

## Dual 2 A, 1.2 V, Slew Rate Controlled Load Switch

### DESCRIPTION

SiP32413, SiP32414, and SiP32416 are slew rate controlled load switches that is designed for 1.1 V to 5.5 V operation.

The devices guarantee low switch on-resistance at 1.2 V input. SiP32413 and SiP32414 feature a controlled soft-on slew rate of typical 150  $\mu$ s that limits the inrush current for designs of capacitive load or noise sensitive loads. SiP32416 features a longer slew rate of typical 2.5 ms to keep the peak of the inrush current even lower.

The devices feature a low voltage control logic interface (on/off interface) that can interface with low voltage digital control without extra level shifting circuit. The SiP32414 and SiP32416 also integrate output discharge switches that enable fast shutdown load discharge. When the switches are off, they provide the reverse blocking to prevent high current flowing into the power source.

All SiP32413, SiP32414, and SiP32416 are available in TDFN8 2.0 mm x 2.0 mm package. Each switch in each device can support over 2 A of continuous current.

### FEATURES

- 1.1 V to 5.5 V operation voltage range
- 62 m $\Omega$  typical from 2 V to 5 V
- Low  $R_{ON}$  down to 1.2 V
- Slew rate controlled turn-on:  
150  $\mu$ s at 3.6 V for SiP32413, SiP32414  
2.5 ms at 3.6 V for SiP32416
- Fast shutdown load discharge for SiP32414 and SiP32416
- Low quiescent current  
< 1  $\mu$ A when disabled  
6.7  $\mu$ A at  $V_{IN} = 1.2$  V
- Switch off reversed blocking
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### APPLICATIONS

- Cellular phones
- Portable media players
- Digital camera
- GPS
- Computers
- Portable instruments and healthcare devices

### TYPICAL APPLICATION CIRCUIT

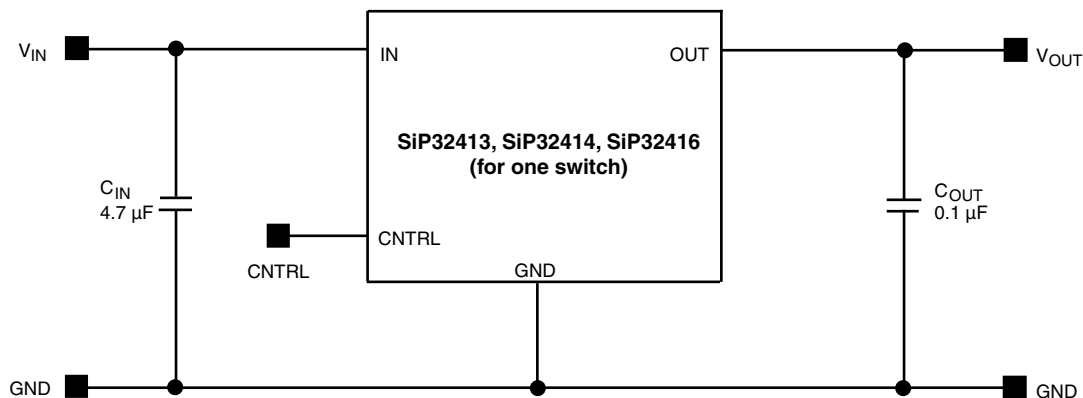


Fig. 1 - SiP32413, SiP32414, SiP32416 Typical Application Circuit

ORDERING INFORMATION			
TEMPERATURE RANGE	PACKAGE	MARKING	PART NUMBER
-40 °C to 85 °C	TDFN8 2.0 mm x 2.0 mm	AA	SiP32413DNP-T1-GE4
		AB	SiP32414DNP-T1-GE4
		AG	SiP32416DNP-T1-GE4

#### Note

- -GE4 denotes halogen-free and RoHS-compliant



ABSOLUTE MAXIMUM RATINGS		
PARAMETER	LIMIT	UNIT
Supply input voltage ( $V_{IN}$ )	-0.3 to 6	V
Enable input voltage ( $V_{EN}$ )	-0.3 to 6	
Output voltage ( $V_{OUT}$ )	-0.3 to 6	
Maximum continuous switch current ( $I_{max.}$ )	2.4	A
Maximum pulsed current (pulsed at 1 ms, 10 % duty cycle)	3	
ESD rating (HBM)	4000	V
Storage temperature ( $T_{stg}$ )	-65 to +150	°C
Thermal resistance ( $\theta_{JA}$ ) <sup>a</sup>	95	°C/W
Power dissipation ( $P_D$ ) <sup>a</sup>	580	mW

**Notes**

- a. Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout  
b. Derate 10.5 mW/°C above  $T_A = 70$  °C, see PCB layout

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings/conditions for extended periods may affect device reliability.

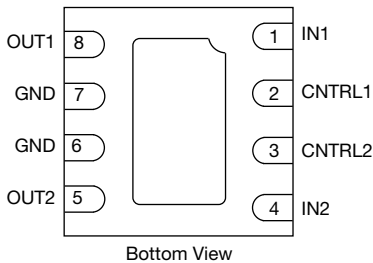
RECOMMENDED OPERATING RANGE		
PARAMETER	LIMIT	UNIT
Input voltage range ( $V_{IN}$ )	1.1 to 5.5	V
Operating junction temperature range ( $T_J$ )	-40 to +125	°C

SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 5$ V, $T_A = -40$ °C to 85 °C (typical values are at $T_A = 25$ °C)	LIMITS -40 °C to 85 °C			UNIT
			MIN. <sup>a</sup>	TYP. <sup>b</sup>	MAX. <sup>a</sup>	
Operating voltage <sup>c</sup>	$V_{IN}$		1.1	-	5.5	V
Quiescent current	$I_Q$	$V_{IN} = 1.2$ V, CNTRL = active	-	6.7	14	$\mu$ A
		$V_{IN} = 1.8$ V, CNTRL = active	-	14	24	
		$V_{IN} = 2.5$ V, CNTRL = active	-	25	40	
		$V_{IN} = 3.6$ V, CNTRL = active	-	40	60	
		$V_{IN} = 4.3$ V, CNTRL = active	-	52	75	
Off supply current	$I_{Q(off)}$	CNTRL = inactive, OUT = open	-	-	1	
Off switch current	$I_{DS(off)}$	CNTRL = inactive, OUT = 0	-	-	1	
Reverse blocking current	$I_{RB}$	$V_{OUT} = 5$ V, $V_{IN} = 1.2$ V, $V_{EN} =$ inactive	-	-	10	
On-resistance	$R_{DS(on)}$	$V_{IN} = 1.2$ V, $I_L = 100$ mA, $T_A = 25$ °C	-	66	76	m $\Omega$
		$V_{IN} = 1.8$ V, $I_L = 100$ mA, $T_A = 25$ °C	-	62	72	
		$V_{IN} = 2.5$ V, $I_L = 100$ mA, $T_A = 25$ °C	-	62	72	
		$V_{IN} = 3.6$ V, $I_L = 100$ mA, $T_A = 25$ °C	-	62	72	
		$V_{IN} = 4.3$ V, $I_L = 100$ mA, $T_A = 25$ °C	-	62	72	
On-resistance temp. coefficient	$TC_{RDS}$		-	3900	-	ppm/°C
CNTRL input low voltage <sup>c</sup>	$V_{IL}$	$V_{IN} = 1.2$ V	-	-	0.3	V
		$V_{IN} = 1.8$ V	-	-	0.4 <sup>d</sup>	
		$V_{IN} = 2.5$ V	-	-	0.5 <sup>d</sup>	
		$V_{IN} = 3.6$ V	-	-	0.6 <sup>d</sup>	
		$V_{IN} = 4.3$ V	-	-	0.7 <sup>d</sup>	
		$V_{IN} = 5$ V	-	-	0.8 <sup>d</sup>	

SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 5\text{ V}$ , $T_A = -40\text{ }^\circ\text{C}$ to $85\text{ }^\circ\text{C}$ (typical values are at $T_A = 25\text{ }^\circ\text{C}$ )	LIMITS -40 °C to 85 °C			UNIT
			MIN. <sup>a</sup>	TYP. <sup>b</sup>	MAX. <sup>a</sup>	
CNTRL input high voltage <sup>c</sup>	$V_{IH}$	$V_{IN} = 1.2\text{ V}$	0.9 <sup>d</sup>	-	-	V
		$V_{IN} = 1.8\text{ V}$	1.2 <sup>d</sup>	-	-	
		$V_{IN} = 2.5\text{ V}$	1.4 <sup>d</sup>	-	-	
		$V_{IN} = 3.6\text{ V}$	1.6 <sup>d</sup>	-	-	
		$V_{IN} = 4.3\text{ V}$	1.7 <sup>d</sup>	-	-	
		$V_{IN} = 5\text{ V}$	1.8	-	-	
EN input leakage	$I_{SINK}$	$V_{EN} = 5.5\text{ V}$	-	-	1	$\mu\text{A}$
Output pull-down resistance	$R_{PD}$	CNTRL = inactive, $T_A = 25\text{ }^\circ\text{C}$ (for SiP32414 and SiP32416 only)	-	217	280	$\Omega$
Output turn-on delay time	$t_{d(on)}$	SiP32413, SiP32414 $V_{IN} = 3.6\text{ V}$ , $R_{LOAD} = 10\ \Omega$ , $C_{LOAD} = 0,1\ \mu\text{F}$ , $T_A = 25\text{ }^\circ\text{C}$	-	140	210	$\mu\text{s}$
Output turn-on rise time	$t_{(on)}$		80	150	220	
Output turn-off delay time	$t_{d(off)}$		-	0.27	1	
Output turn-on delay time	$t_{d(on)}$	SiP32416 $V_{IN} = 3.6\text{ V}$ , $R_{LOAD} = 10\ \Omega$ , $C_{LOAD} = 0,1\ \mu\text{F}$ , $T_A = 25\text{ }^\circ\text{C}$	-	2	-	ms
Output turn-on rise time	$t_{(on)}$		1.2	2.5	3.8	
Output turn-off delay time	$t_{d(off)}$		-	-	0.001	

**Notes**

- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- For  $V_{IN}$  outside this range consult typical EN threshold curve
- Not tested, guarantee by design

**PIN CONFIGURATION**

**Fig. 2 - TDFN8 2.0 mm x 2.0 mm**

PIN DESCRIPTION		
PIN NUMBER	NAME	FUNCTION
1	IN1	This is the input pin of the switch side 1
2	CNTRL1	This is the control pin of the switch side 1
3	CNTRL2	This is the control pin of the switch side 2
4	IN2	This is the input pin of the switch side 2
5	OUT2	This is the output pin of the switch side 2
6	GND	Ground connection
7	GND	Ground connection
8	OUT1	This is the output pin of the switch side 1



TRUTH TABLE SiP32413			
CNTRL1	CNTRL2	SW1	SW2
0	0	On	Off
0	1	On	On
1	0	Off	Off
1	1	Off	On

TRUTH TABLE SiP32414, SiP32416			
CNTRL1	CNTRL2	SW1	SW2
0	0	Off	Off
0	1	Off	On
1	0	On	Off
1	1	On	On

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

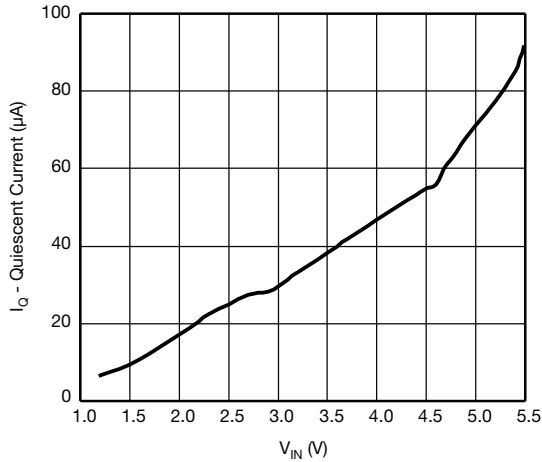


Fig. 3 - Quiescent Current vs. Input Voltage

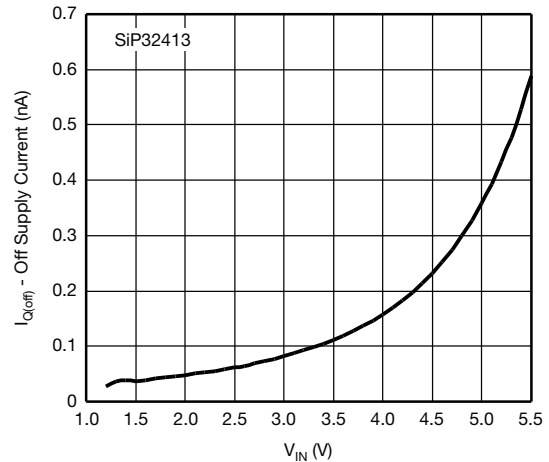


Fig. 5 - SiP32413 Off Supply Current vs. VIN

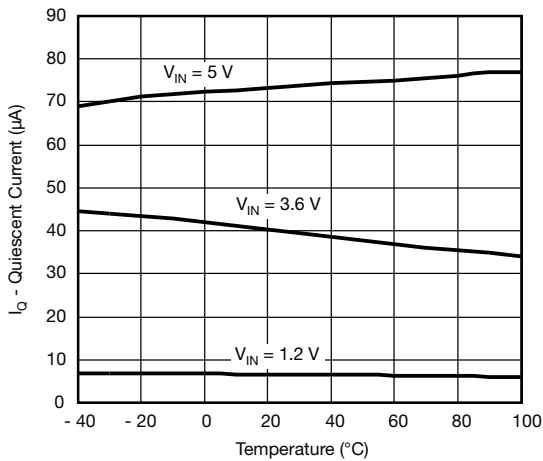


Fig. 4 - Quiescent Current vs. Temperature

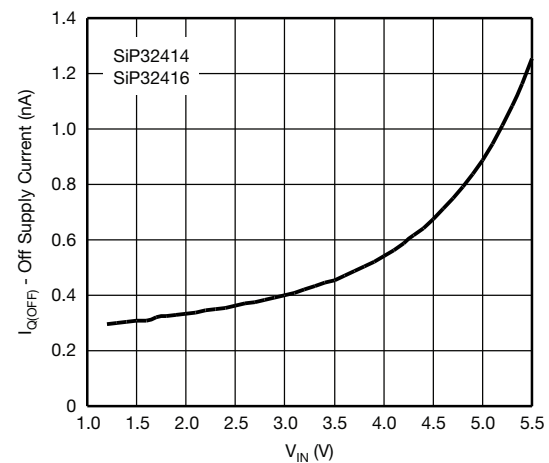


Fig. 6 - SiP32414 and SiP32416 Off Supply Current vs. VIN



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

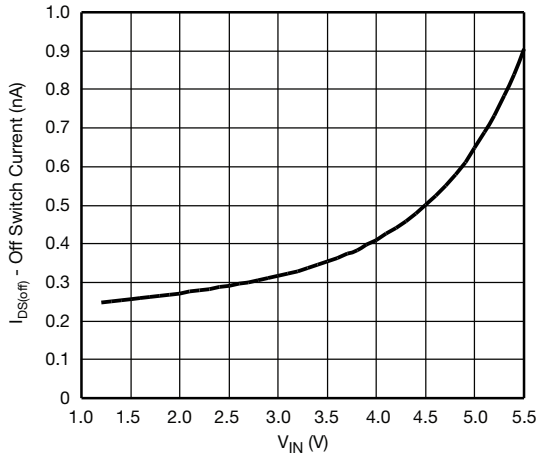


Fig. 7 - Off Switch Current vs. Input Voltage

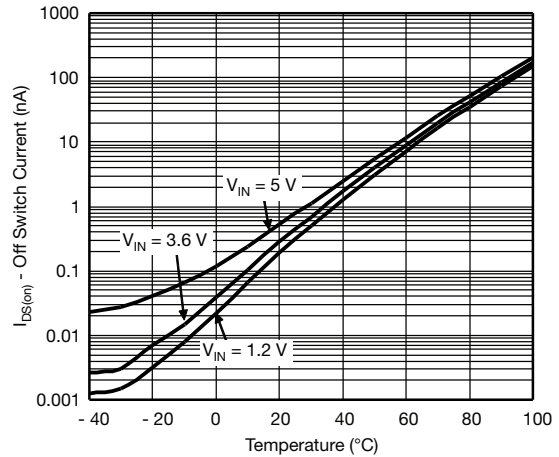


Fig. 10 - Off Switch Current vs. Temperature

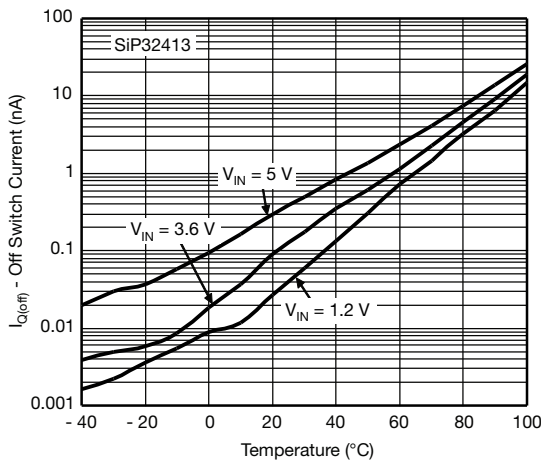


Fig. 8 - SiP32414 Off Supply Current vs. Temperature

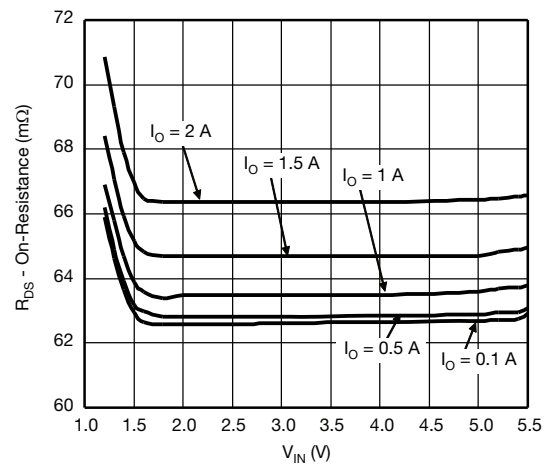


Fig. 11 - R\_DS(on) vs. Input Voltage

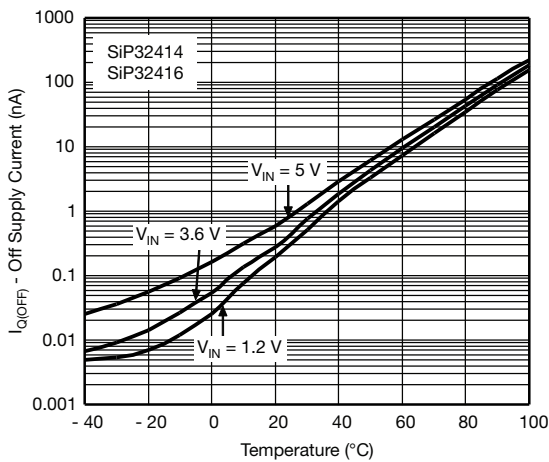


Fig. 9 - SiP32414 and SiP32416 Off Supply Current vs. Temperature

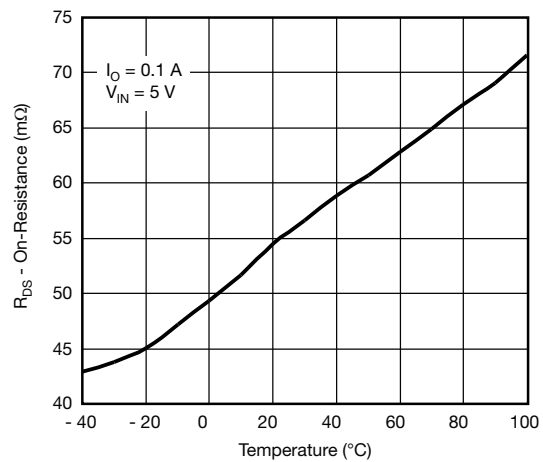
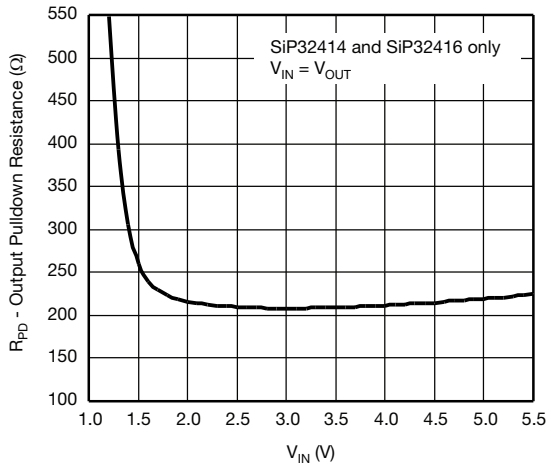
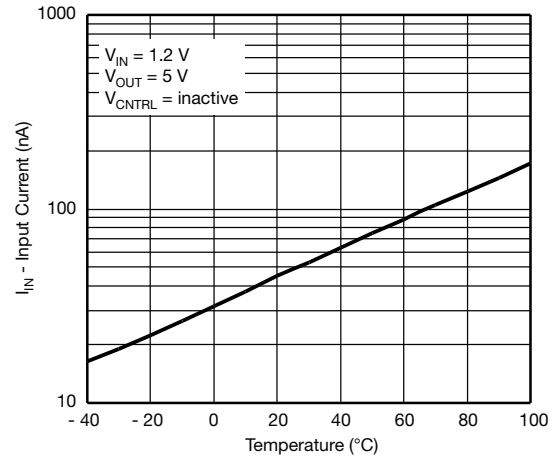


Fig. 12 - R\_DS(on) vs. Temperature

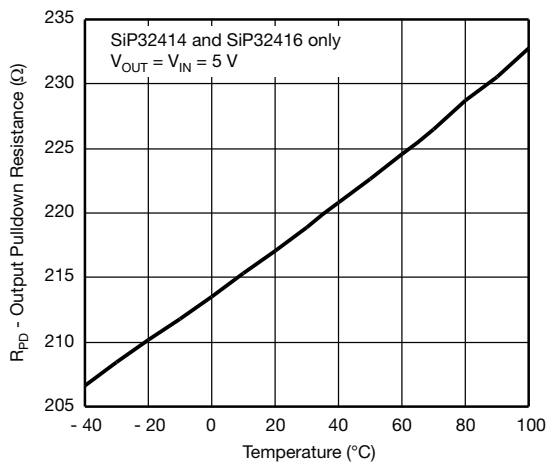
## TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)



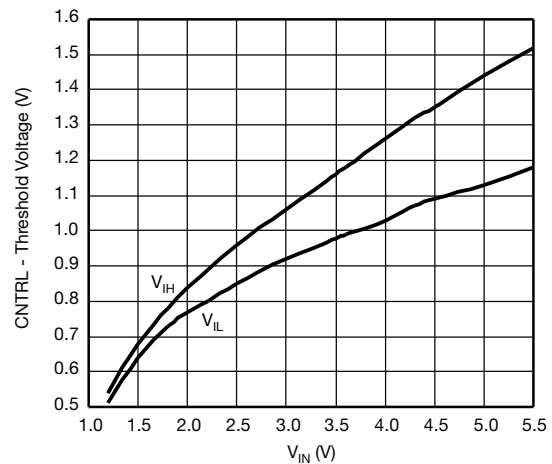
**Fig. 13 - SiP32414 and SiP32416 Output Pull-Down vs. Input Voltage**



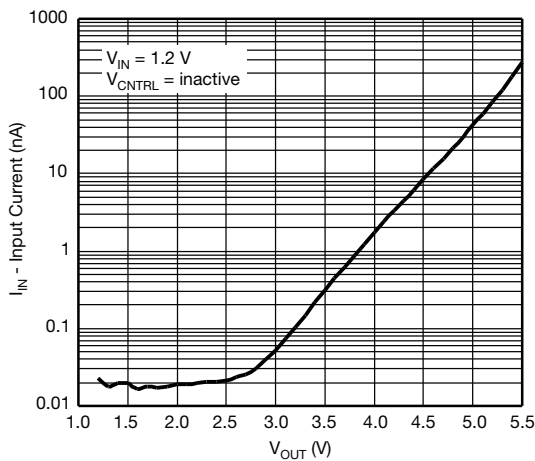
**Fig. 16 - Reverse Blocking Current vs. Temperature**



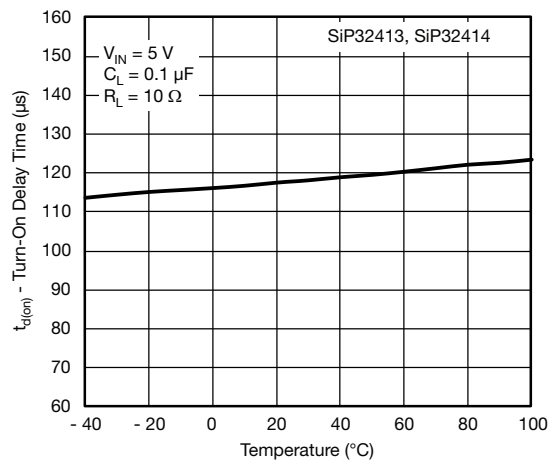
**Fig. 14 - SiP32414 and SiP32416 Output Pull-Down vs. Temperature**



**Fig. 17 - CNTRL Threshold Voltage vs. Input Voltage**



**Fig. 15 - Reverse Blocking Current vs. Output Voltage**



**Fig. 18 - SiP32413 and SiP32414 Turn-On Delay Time vs. Temperature**



## TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

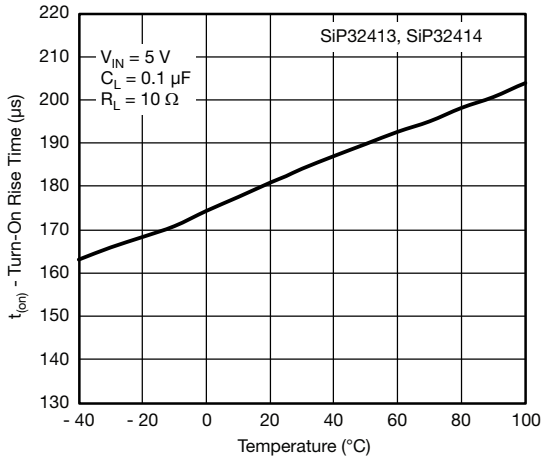


Fig. 19 - SiP32413 and SiP32414 Rise Time vs. Temperature

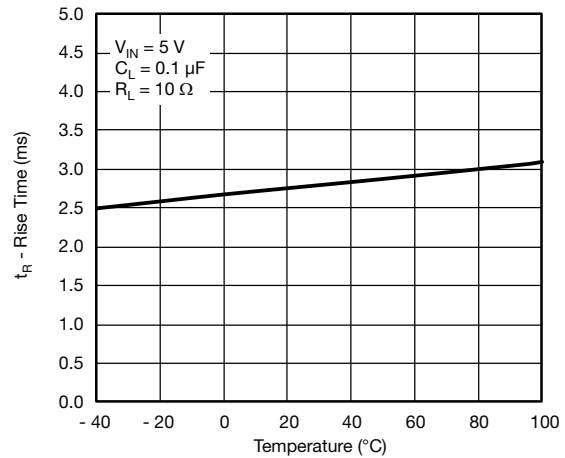


Fig. 22 - SiP32416 Rise Time vs. Temperature

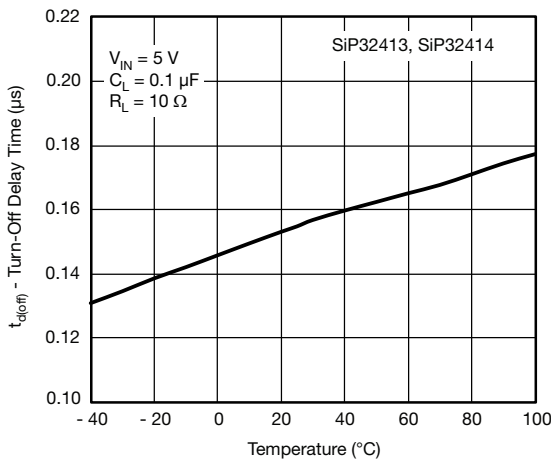


Fig. 20 - SiP32413 and SiP32414 Turn-Off Delay Time vs. Temperature

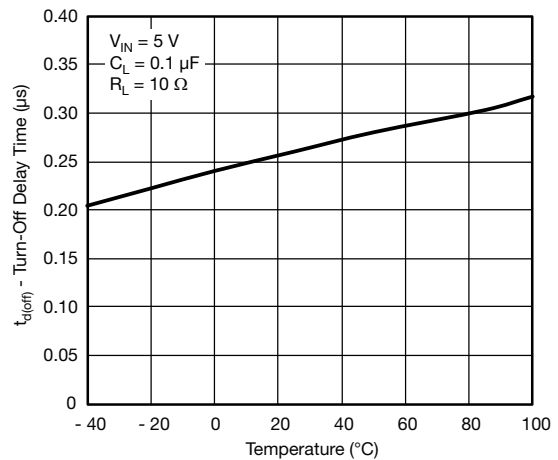


Fig. 23 - SiP32416 Turn-Off Delay Time vs. Temperature

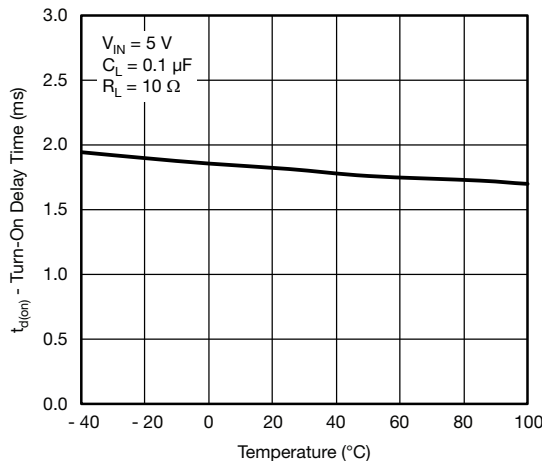


Fig. 21 - SiP32416 Turn-On Delay Time vs. Temperature



TYPICAL WAVEFORMS

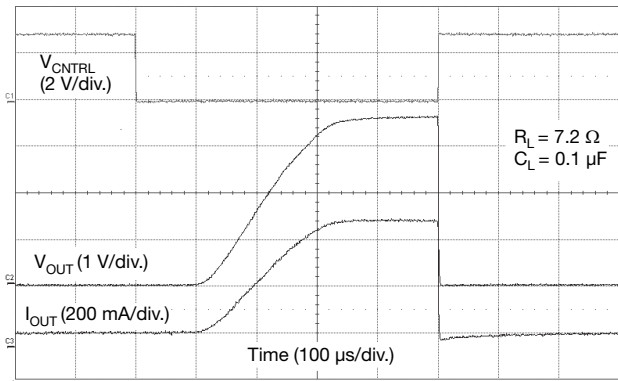


Fig. 24 - SiP32413 Channel 1 Switching (V<sub>IN</sub> = 3.6 V, R<sub>L</sub> = 7.2 Ω)

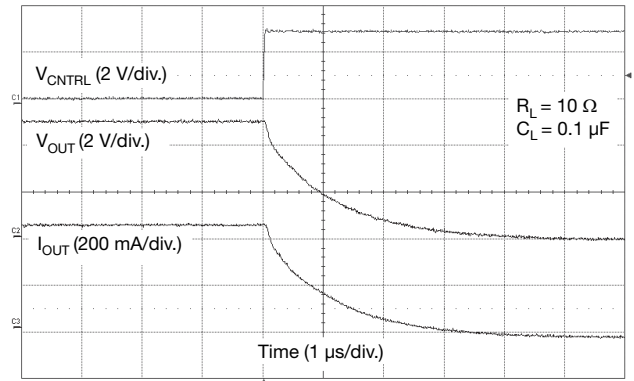


Fig. 27 - SiP32413 Channel 1 Turn-Off (V<sub>IN</sub> = 5 V, R<sub>L</sub> = 10 Ω)

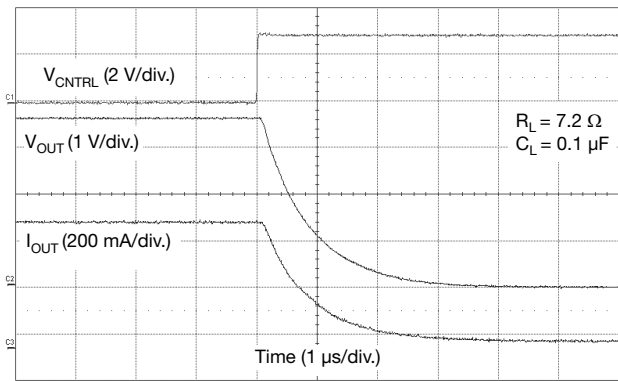


Fig. 25 - SiP32413 Channel 1 Turn-Off (V<sub>IN</sub> = 3.6 V, R<sub>L</sub> = 7.2 Ω)

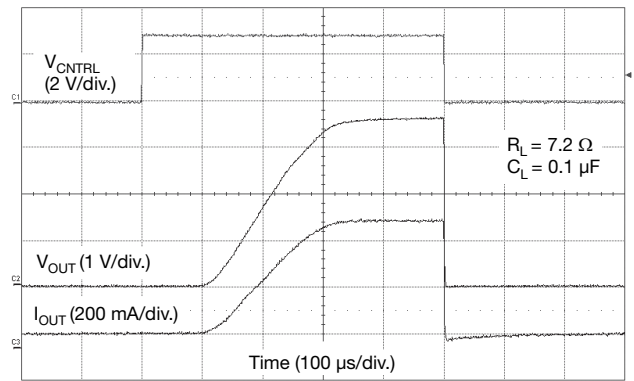


Fig. 28 - SiP32413 Channel 2 and SiP32414 Switching (V<sub>IN</sub> = 3.6 V, R<sub>L</sub> = 7.2 Ω)

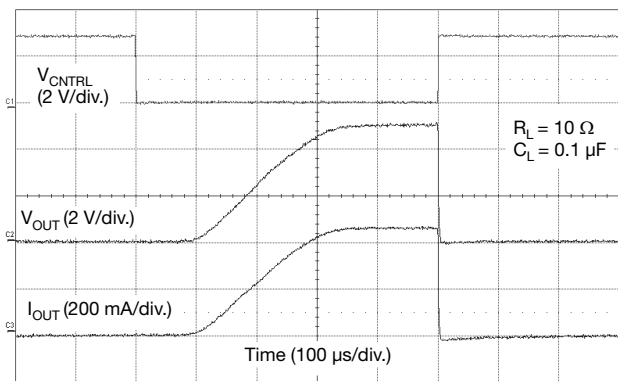


Fig. 26 - SiP32413 Channel 1 Switching (V<sub>IN</sub> = 5 V, R<sub>L</sub> = 10 Ω)

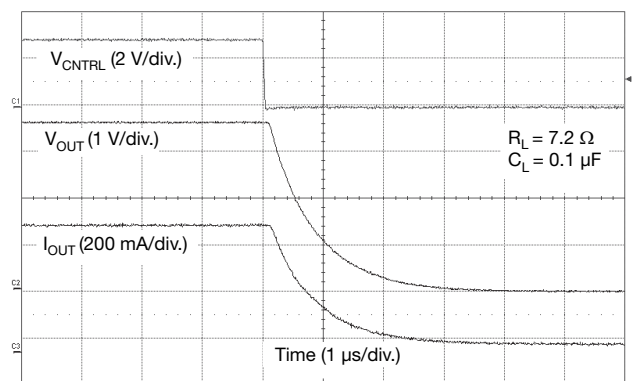
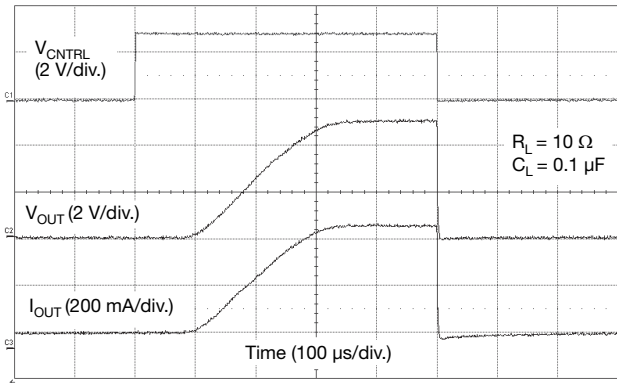
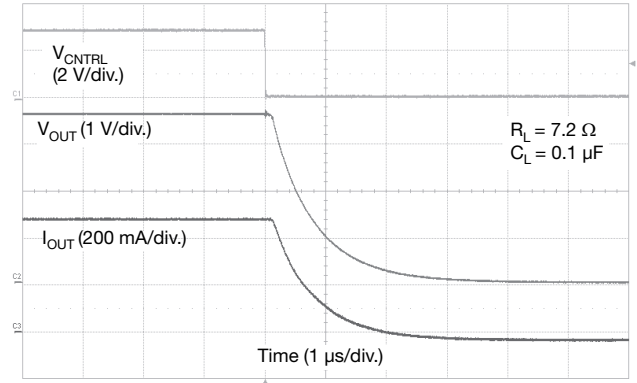


Fig. 29 - SiP32413 Channel 2 and SiP32414 Turn-Off (V<sub>IN</sub> = 3.6 V, R<sub>L</sub> = 7.2 Ω)

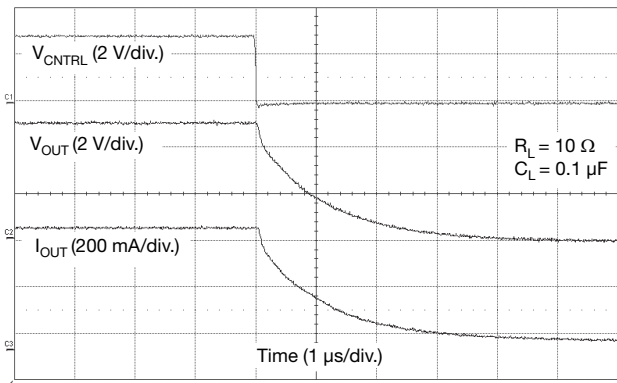




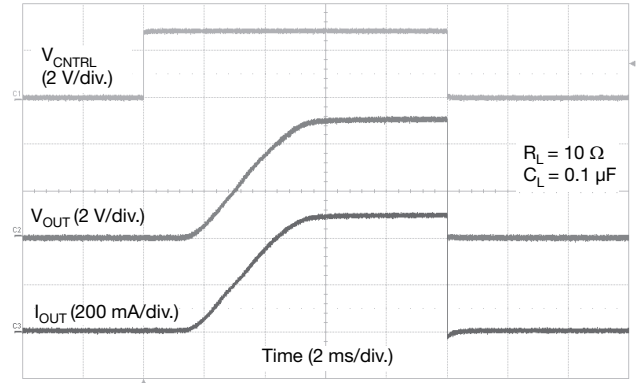
**Fig. 30 - SiP32413 Channel 2 and SiP32414 Switching**  
( $V_{IN} = 5\text{ V}$ ,  $R_L = 10\ \Omega$ )



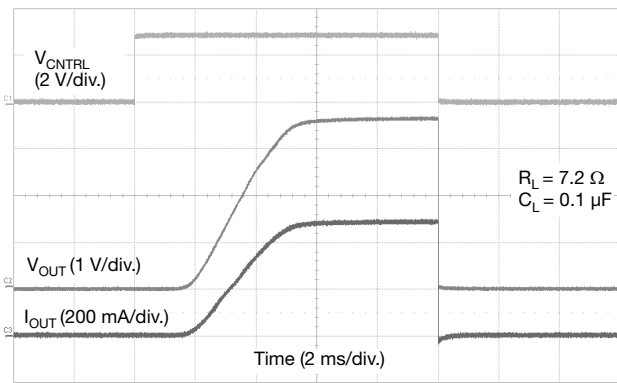
**Fig. 33 - SiP32416 Turn-Off**  
( $V_{IN} = 3.6\text{ V}$ ,  $R_L = 7.2\ \Omega$ )



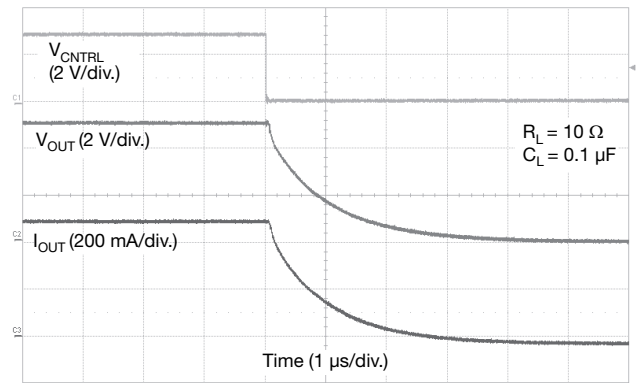
**Fig. 31 - SiP32413 Channel 2 and SiP32414 Turn-Off**  
( $V_{IN} = 5\text{ V}$ ,  $R_L = 10\ \Omega$ )



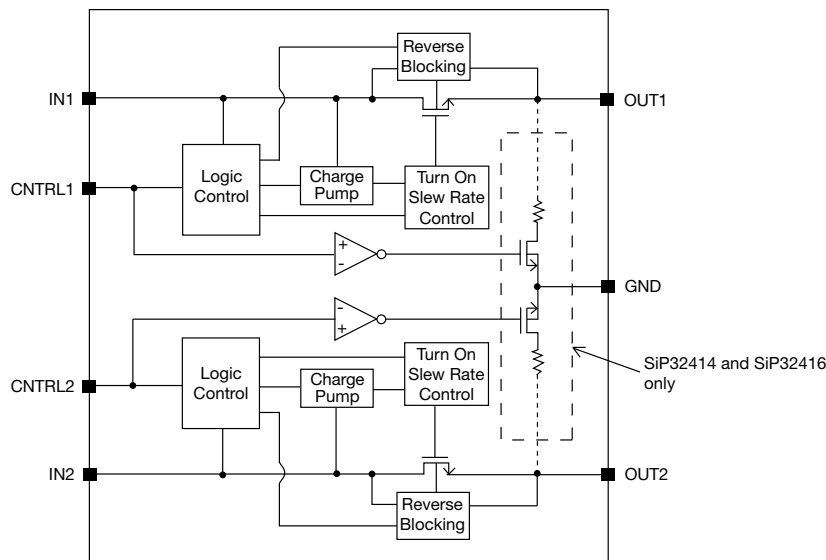
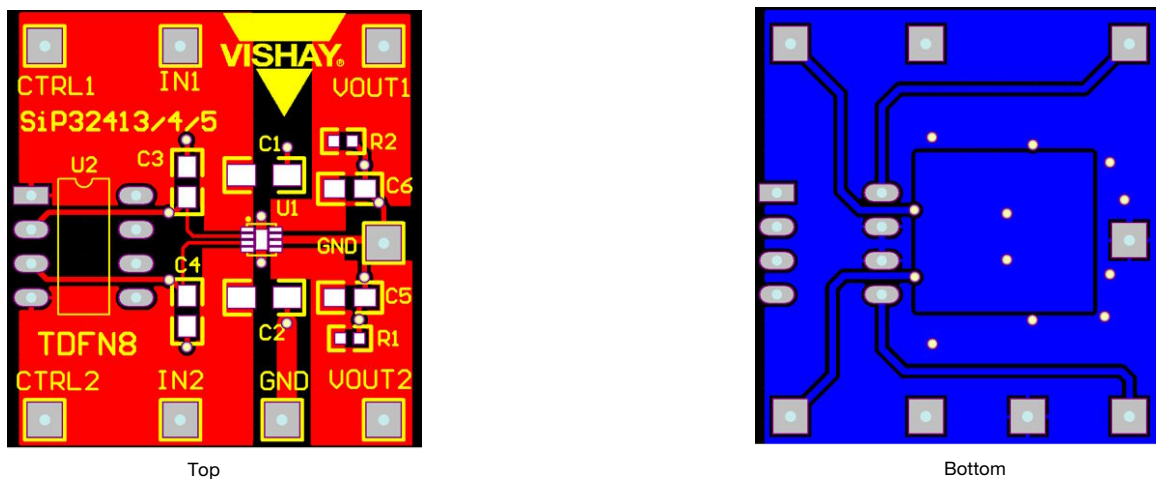
**Fig. 34 - SiP32416 Switching**  
( $V_{IN} = 5\text{ V}$ ,  $R_L = 10\ \Omega$ )



**Fig. 32 - SiP32416 Switching**  
( $V_{IN} = 3.6\text{ V}$ ,  $R_L = 7.2\ \Omega$ )



**Fig. 35 - SiP32416 Turn-Off**  
( $V_{IN} = 5\text{ V}$ ,  $R_L = 10\ \Omega$ )

**BLOCK DIAGRAM**

**Fig. 36 - Functional Block Diagram**
**PCB LAYOUT**

**Fig. 37 - PCB Layout for TDFN8 2.0 mm x 2.0 mm (type: FR4, size: 1.2" x 1.3", thickness: 0.062", copper thickness: 2 oz.)**
**DETAILED DESCRIPTION**

SiP32413, SiP32414, and SiP32416 are dual n-channel power MOSFETs designed as high side load switch with slew rate control to prevent in-rush current. Once enable the device charges the gate of the power MOSFET to 5 V gate to source voltage while controlling the slew rate of the turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. For SiP32414, when disable the output discharge circuit turns on to help pull the output voltage to ground more quickly. For all parts, in disable mode, the reverse blocking circuit is activated to prevent current from going back to the input in case the output voltage is higher than the input voltage. Input voltage is needed for the reverse blocking circuit to work properly, it can be as low as  $V_{IN(min)}$ .

**APPLICATION INFORMATION**
**Input Capacitor**

While bypass capacitors on the inputs are not required, 2.2  $\mu\text{F}$  or larger capacitors for  $C_{IN}$  is recommended in almost all applications. The bypass capacitors should be placed as physically close as possible to the device's input to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.



**Output Capacitor**

A 0.1 μF capacitor or larger across V<sub>OUT</sub> and GND is recommended to insure proper slew operation. C<sub>OUT</sub> may be increased without limit to accommodate any load transient condition with only minimal affect on the turn on slew rate time. There are no ESR or capacitor type requirement.

**Control**

The CNTRL pins are compatible with both TTL and CMOS logic voltage levels.

**Protection Against Reverse Voltage Condition**

SiP32413, SiP32414, and SiP32416 contain reverse blocking circuitries to protect the current from going to the input from the output in case where the output voltage is higher than the input voltage when the main switch is off. Supply voltages as low as the minimum required input voltage are necessary for these circuitries to work properly.

**Thermal Considerations**

All three parts are designed to maintain constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 2.4 A, as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 95) the power pad of the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T<sub>J(max.)</sub> = 125 °C, the junction-to-ambient thermal resistance for the TDFN4 1.2 mm x 1.6 mm package, θ<sub>J-A</sub> = 95 °C/W, and the ambient temperature, T<sub>A</sub>, which may be formulaically expressed as:

$$P \text{ (max.)} = \frac{T_{J(max.)} - T_A}{\theta_{J-A}} = \frac{125 - T_A}{95}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 580 mW.

So long as the load current is below the 2.4 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the R<sub>DS(on)</sub> at the ambient temperature.

As an example let us calculate the worst case maximum load current at T<sub>A</sub> = 70 °C. The worst case R<sub>DS(on)</sub> at 25 °C occurs at an input voltage of 1.2 V and is equal to 75 mΩ. The R<sub>DS(on)</sub> at 70 °C can be extrapolated from this data using the following formula:

$$R_{DS(on)} \text{ (at } 70 \text{ }^\circ\text{C)} = R_{DS(on)} \text{ (at } 25 \text{ }^\circ\text{C)} \times (1 + T_C \times \Delta T)$$

Where T<sub>C</sub> is 3400 ppm/°C. Continuing with the calculation we have

$$R_{DS(on)} \text{ (at } 70 \text{ }^\circ\text{C)} = 75 \text{ m}\Omega \times (1 + 0.0034 \times (70 \text{ }^\circ\text{C} - 25 \text{ }^\circ\text{C})) = 86.5 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD(max.)} < \sqrt{\frac{P \text{ (max.)}}{R_{DS(on)}}}$$

which in case is 2.6 A, assuming one switch turn on at a time. Under the stated input voltage condition, if the 2.6 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

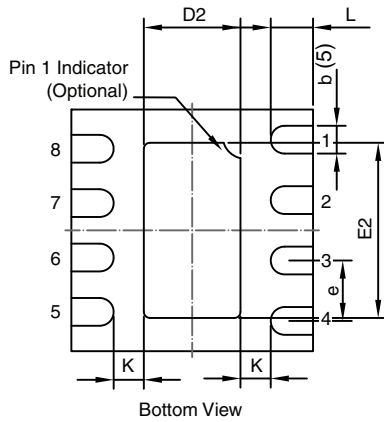
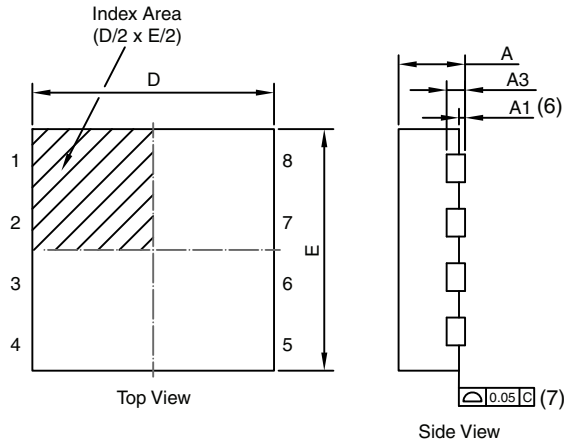
To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 2.4 A only as listed in the Absolute Maximum Ratings table.



<b>PRODUCT SUMMARY</b>			
Part number	SiP32413	SiP32414	SiP32416
Description	Dual switch, 1.1 V to 5.5 V, 150 $\mu$ s rise time, reversed EN logic	1.1 V to 5.5 V, 150 $\mu$ s rise time, output discharge	1.1 V to 5.5 V, 2.5 ms rise time, output discharge
Configuration	Dual	Dual	Dual
Slew rate time ( $\mu$ s)	150	150	2500
On delay time ( $\mu$ s)	140	140	2000
Input voltage min. (V)	1.1	1.1	1.1
Input voltage max. (V)	5.5	5.5	5.5
On-resistance at input voltage min. ( $m\Omega$ )	66	66	66
On-resistance at input voltage max. ( $m\Omega$ )	62	62	62
Quiescent current at input voltage min. ( $\mu$ A)	6.7	6.7	6.7
Quiescent current at input voltage max. ( $\mu$ A)	71	71	71
Output discharge (yes / no)	No	Yes	Yes
Reverse blocking (yes / no)	Yes	Yes	Yes
Continuous current (A)	2.4	2.4	2.4
Package type	TDFN8	TDFN8	TDFN8
Package size (W, L, H) (mm)	2.0 x 2.0 x 0.5	2.0 x 2.0 x 0.5	2.0 x 2.0 x 0.5
Status code	2	2	2
Product type	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

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## Case Outline for TDFN8 2 x 2



DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.50	0.55	0.60	0.020	0.022	0.024
A1	0.00	-	0.05	0.000	-	0.002
A3	0.152 REF			0.006 REF		
b	0.18	0.23	0.28	0.007	0.009	0.011
D	1.95	2.00	2.05	0.077	0.079	0.081
D2	0.75	0.80	0.85	0.030	0.031	0.033
e	0.50 BSC			0.020 BSC		
E	1.95	2.00	2.05	0.077	0.079	0.081
E2	1.40	1.45	1.50	0.055	0.057	0.059
K	-	0.25	-	-	0.010	-
L	0.30	0.35	0.40	0.012	0.014	0.016

ECN: T15-0301-Rev. B, 29-Jun-15  
DWG: 5997

### Note

- (1) All dimensions are in millimeters which will govern.
- (2) Max. package warpage is 0.05 mm.
- (3) Max. allowable burrs is 0.076 mm in all directions.
- (4) Pin #1 ID on top will be laser/ink marked.
- (5) Dimension applies to metallized terminal and is measured between 0.20 mm and 0.25 mm from terminal tip.
- (6) Applied only for terminals.
- (7) Applied for exposed pad and terminals.



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